

LM4040 高精度マイクロパワー シャント電圧リファレンス

1 特長

- 2.048V、2.5V、3V、4.096V、5V、8.192V、10V の固定出力電圧
- 厳しい出力許容誤差と小さい温度係数
 - 最大 0.1%、100ppm/°C – A グレード
 - 最大 0.2%、100ppm/°C – B グレード
 - 最大 0.5%、100ppm/°C – C グレード
 - 最大 1.0%、150ppm/°C – D グレード
- 低い出力ノイズ: 35 μ V_{RMS} (標準値)
- 広い動作電流範囲: 15mA に対し 45 μ A (標準値)
- 容量性負荷の大小にかかわらず安定して動作するため、出力コンデンサは不要
- 拡張温度範囲で利用可能: -40°C ~ 125°C

2 アプリケーション

- データアキュイジションシステム
- エネルギーインフラ
- アナログ入力モジュール
- フィールドトランスミッタ
- 高精度オーディオ
- 車載用電子機器

3 概要

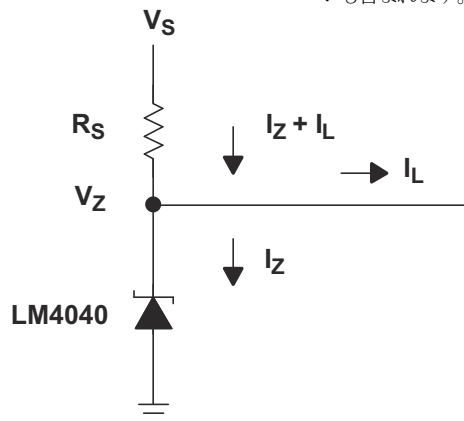
LM4040 シリーズのシャント電圧リファレンスは、多様なアプリケーション向けに作られた、汎用性が高く使いやすい基準電圧です。これは 2 ピンの固定出力デバイスで、外付けコンデンサを必要とせず、容量性負荷の大小にかかわらず安定して動作します。また、この基準電圧はダイナミックインピーダンス、ノイズ、温度係数が小さく、広範囲の動作電流および温度にわたって安定した電圧を維持します。LM4040 では、ウェハーソート時のヒューズとツェナーザップ逆方向ブレイクダウンによる電圧調整を使用して、最大 0.1% (A グレード) から最大 1% (D グレード) までの 4 種類の出力電圧許容誤差の製品を提供しています。このため、アプリケーションに適した最良のコスト / 性能比を非常に柔軟に選択できます。

省スペースの SC-70 と SOT-23-3 にパッケージ化され、最低電流 45 μ A (標準値) で動作する LM4040 は、ポータブルアプリケーションにも理想的です。LM4040xI は -40°C ~ 85°C の周囲温度範囲で動作します。LM4040xQ は -40°C ~ 125°C の周囲温度範囲で動作します。

製品情報

部品番号	パッケージ (ピン) ⁽¹⁾	本体サイズ (公称) ⁽²⁾
LM4040	SOT-23 (3)	2.92mm × 1.30mm
	SC70 (6)	2.00mm × 1.25mm

- (1) 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。
- (2) パッケージサイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



概略回路図



Table of Contents

1 特長	1	6.17 LM4040C50I, LM4040D50I Electrical Characteristics.....	18
2 アプリケーション	1	6.18 LM4040C50Q, LM4040D50Q Electrical Characteristics.....	19
3 概要	1	6.19 LM4040A82I, LM4040B82I Electrical Characteristics.....	20
4 Device Comparison Table	3	6.20 LM4040C82I, LM4040D82I Electrical Characteristics.....	21
5 Pin Configuration and Functions	4	6.21 LM4040A10I, LM4040B10I Electrical Characteristics.....	22
6 Specifications	5	6.22 LM4040C10I, LM4040D10I Electrical Characteristics.....	23
6.1 Absolute Maximum Ratings.....	5	6.23 Typical Characteristics.....	24
6.2 ESD Ratings.....	5	7 Detailed Description	25
6.3 Recommended Operating Conditions.....	5	7.1 Overview.....	25
6.4 Thermal Information.....	5	7.2 Functional Block Diagram.....	25
6.5 LM4040A20I, LM4040B20I Electrical Characteristics.....	6	7.3 Feature Description.....	25
6.6 LM4040C20I, LM4040D20I Electrical Characteristics.....	7	7.4 Device Functional Modes.....	25
6.7 LM4040C20Q, LM4040D20Q Electrical Characteristics.....	8	8 Applications and Implementation	26
6.8 LM4040A25I, LM4040B25I Electrical Characteristics.....	9	8.1 Application Information.....	26
6.9 LM4040C25I, LM4040D25I Electrical Characteristics.....	10	8.2 Typical Applications.....	26
6.10 LM4040C25Q, LM4040D25Q Electrical Characteristics.....	11	8.3 Power Supply Recommendations.....	28
6.11 LM4040A30I, LM4040B30I Electrical Characteristics.....	12	8.4 Layout.....	28
6.12 LM4040C30I, LM4040D30I Electrical Characteristics.....	13	9 Device and Documentation Support	30
6.13 LM4040C30Q, LM4040D30Q Electrical Characteristics.....	14	9.1 Related Links.....	30
6.14 LM4040A41I, LM4040B41I Electrical Characteristics.....	15	9.2 Trademarks.....	30
6.15 LM4040C41I, LM4040D41I Electrical Characteristics.....	16	9.3 静電気放電に関する注意事項.....	30
6.16 LM4040A50I, LM4040B50I Electrical Characteristics.....	17	9.4 用語集.....	30
		10 Revision History	30
		11 Mechanical, Packaging, and Orderable Information	31

4 Device Comparison Table

T_A	DEVICE GRADE	V_{KA}	ORDERABLE ⁽¹⁾ PART NUMBER
-40°C to 85°C	A grade: 0.1% initial accuracy and 100 ppm/°C temperature coefficient	2.048V	LM4040A20I
		2.5V	LM4040A25I
		3V	LM4040A30I
		4.096V	LM4040A41I
		5V	LM4040A50I
		8.192V	LM4040A82I
		10V	LM4040A10I
	B grade: 0.2% initial accuracy and 100 ppm/°C temperature coefficient	2.048V	LM4040B20I
		2.5V	LM4040B25I
		3V	LM4040B30I
		4.096V	LM4040B41I
		5V	LM4040B50I
		8.192V	LM4040B82I
		10V	LM4040B10I
-40°C to 85°C	C grade: 0.5% initial accuracy and 100 ppm/°C temperature coefficient	2.048V	LM4040C20I
		2.5V	LM4040C25I
		3V	LM4040C30I
		4.096V	LM4040C41I
		5V	LM4040C50I
		8.192V	LM4040C82I
-40°C to 85°C	D grade: 1.0% initial accuracy and 150 ppm/°C temperature coefficient	2.048V	LM4040D20I
		2.5V	LM4040D25I
		3V	LM4040D30I
		4.096V	LM4040D41I
		5V	LM4040D50I
		8.192V	LM4040D82I
-40°C to 125°C	C grade: 0.5% initial accuracy and 100 ppm/°C temperature coefficient	2.048V	LM4040C20Q
		2.5V	LM4040C25Q
		3V	LM4040C30Q
		5V	LM4040C50Q
	D grade: 1.0% initial accuracy and 150 ppm/°C temperature coefficient	2.048V	LM4040D20Q
		2.5V	LM4040D25Q
		3V	LM4040D30Q
		5V	LM4040D50Q

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

5 Pin Configuration and Functions

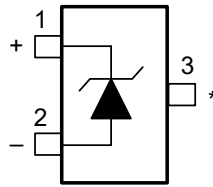


図 5-1. DBZ Package
 3-Pin SOT-23
 Top View

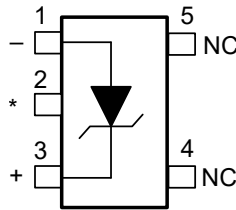


図 5-2. DCK Package
 5-Pin SC70
 Top View

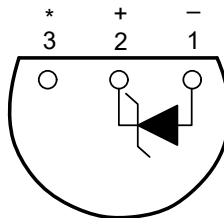


図 5-3. LP Package
 3-Pin TO-92
 Bottom View

Pin Functions

NAME	PIN			TYPE	DESCRIPTION
	DBZ	DCK	TO-92		
CATHODE	1	3	2	I/O	Shunt Current/Voltage input
ANODE	2	1	1	O	Common pin, normally connected to ground
NC	—	4, 5	—	I	No Internal Connection
*	3	2	3	I	Substrate Connection. Must float or connect to anode.

6 Specifications

6.1 Absolute Maximum Ratings

over free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
I_Z	Continuous cathode current	-10	25	mA
T_J	Operating virtual junction temperature		150	°C
T_{stg}	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under [セクション 6.3](#) is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
 (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

			MIN	MAX	UNIT
I_Z	Cathode current		(1)	15	mA
T_A	Free-air temperature	LM4040xxxI	-40	85	°C
		LM4040xxxQ	-40	125	

- (1) See parametric tables

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LM4040		UNIT
		DBZ	DCK	
		3 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	206	252	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 LM4040A20I, LM4040B20I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040A20I			LM4040B20I			UNIT			
			MIN	TYP	MAX	MIN	TYP	MAX				
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			2.048			V			
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-2 2			mV			
			Full range			-15 15						
$I_{Z,\text{min}}$	Minimum cathode current		25°C			45 75			μA			
			Full range			80 80						
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 20			ppm/°C			
			25°C	$I_Z = 1\text{mA}$			± 15					
				Full range			± 100					
			25°C			$I_Z = 100\mu\text{A}$				± 15		
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.3 0.8			mV			
			Full range			1 1						
			25°C			$1\text{mA} < I_Z < 15\text{mA}$				2.5 6		
			Full range			8 8						
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.3 0.8			Ω			
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			35 35			μV_{RMS}			
	Long-term stability of reverse breakdown voltage	$t = 1000\text{h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120 120			ppm			
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08% 0.08%			—			

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
 A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
 C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.6 LM4040C20I, LM4040D20I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C20I			LM4040D20I			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			2.048			V	
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-10	10		mV	
			Full range			-23	23			
$I_{Z,\text{min}}$	Minimum cathode current		25°C			45	75		μA	
			Full range			80				
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 20			ppm/°C	
			$I_Z = 1\text{mA}$	25°C			± 15			
				Full range			± 100			
			$I_Z = 100\mu\text{A}$	25°C			± 15			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.3	0.8		mV	
			Full range			1				
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			2.5		6		
			Full range			8				
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.3	0.9		Ω	
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			35		μV_{RMS}		
	Long-term stability of reverse breakdown voltage	$t = 1000\text{h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120		ppm		
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%		—		

(1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .

(2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:

A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:

C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.7 LM4040C20Q, LM4040D20Q Electrical Characteristics

at extended temperature range, full-range $T_A = -40^\circ\text{C}$ to 125°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C20Q			LM4040D20Q			UNIT			
			MIN	TYP	MAX	MIN	TYP	MAX				
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			2.048			V			
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-10	10		mV			
			Full range			-30	30					
$I_{Z,\text{min}}$	Minimum cathode current		25°C			45	75		μA			
			Full range			80						
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 20			ppm/°C			
			25°C	$I_Z = 1\text{mA}$			± 15					
				Full range			± 100					
			25°C			$I_Z = 100\mu\text{A}$				± 15		
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.3	0.8		mV			
			Full range			1						
			25°C			$1\text{mA} < I_Z < 15\text{mA}$				2.5	6	
			Full range			8						
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.3	0.9		Ω			
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			35			μV_{RMS}			
	Long-term stability of reverse breakdown voltage	$t = 1000\text{h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm			
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—			

(1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .

(2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:

A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:

C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.8 LM4040A25I, LM4040B25I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040A25I			LM4040B25I			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			2.5			V	
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-2.5 2.5			mV	
			Full range			-19 19 -21 21				
$I_{Z,\text{min}}$	Minimum cathode current		25°C			45 75 45 75			μA	
			Full range			80 80				
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 20			ppm/°C	
			$I_Z = 1\text{mA}$	25°C			± 15			
				Full range			± 100			
			$I_Z = 100\mu\text{A}$	25°C			± 15			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.3 0.8 0.3 0.8			mV	
			Full range			1 1				
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			2.5 6 2.5 6				
			Full range			8 8				
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.3 0.8 0.3 0.8			Ω	
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			35 35			μV_{RMS}	
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120 120			ppm	
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08% 0.08%			—	

(1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .

(2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:

A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:

C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.9 LM4040C25I, LM4040D25I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C25I			LM4040D25I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25			2.5			V
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25			-25			mV
			Full range			-49			
$I_{Z,\text{min}}$	Minimum cathode current		25			45			μA
			Full range			80			
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25			± 20			ppm/ $^\circ\text{C}$
			25			± 15			
			Full range			± 100			
			25			± 15			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25			0.3			mV
			Full range			1			
		$1\text{mA} < I_Z < 15\text{mA}$	25			2.5			
			Full range			8			
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25			0.3			Ω
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25			35			μV_{RMS}
	Long-term stability of reverse breakdown voltage	$t = 1000\text{h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
 A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
 C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.10 LM4040C25Q, LM4040D25Q Electrical Characteristics

at extended temperature range, full-range $T_A = -40^\circ\text{C}$ to 125°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C25Q			LM4040D25Q			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25			2.5			V
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25			-25			mV
			Full range			-63			
$I_{Z,\text{min}}$	Minimum cathode current		25			45			μA
			Full range			80			
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25			± 20			ppm/ $^\circ\text{C}$
			25			± 15			
		$I_Z = 1\text{mA}$	Full range			± 100			
			25			± 15			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25			0.3			mV
			Full range			1			
		$1\text{mA} < I_Z < 15\text{mA}$	25			2.5			
			Full range			8			
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25			0.3			Ω
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25			35			μV_{RMS}
	Long-term stability of reverse breakdown voltage	$t = 1000\text{h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.11 LM4040A30I, LM4040B30I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040A30I			LM4040B30I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			3			V
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-3 3			mV
			Full range			-22 22			
$I_{Z,\text{min}}$	Minimum cathode current		25°C			47 77			μA
			Full range			82 82			
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$ $I_Z = 1\text{mA}$ $I_Z = 100\mu\text{A}$	25°C			± 20			ppm/°C
			25°C			± 15			
			Full range			± 100			
			25°C			± 15			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.6 0.8			mV
			Full range			1.1 1.1			
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			2.7 6			
			Full range			9 9			
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.4 0.9			Ω
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			35			μV_{RMS}
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
 A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
 C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.12 LM4040C30I, LM4040D30I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C30I			LM4040D30I			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			3			V	
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-15 15			mV	
			Full range			-34 34 -59 59				
$I_{Z,\text{min}}$	Minimum cathode current		25°C			45 77			μA	
			Full range			82 82				
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 20			ppm/°C	
			$I_Z = 1\text{mA}$	25°C			± 15			
				Full range			± 100 ± 150			
			$I_Z = 100\mu\text{A}$	25°C			± 15 ± 15			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.4 0.8 1.4 1			mV	
			Full range			1.1 1.3				
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			2.7 6 2.7 8				
			Full range			9 11				
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.4 0.9 0.4 1.2			Ω	
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			35 35			μV_{RMS}	
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120 120			ppm	
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08% 0.08%			—	

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.13 LM4040C30Q, LM4040D30Q Electrical Characteristics

at extended temperature range, full-range $T_A = -40^\circ\text{C}$ to 125°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C30Q			LM4040D30Q			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			3			V
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-15 15			mV
			Full range			-45 45			
$I_{Z,\text{min}}$	Minimum cathode current		25°C			47 77			μA
			Full range			82 82			
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$ $I_Z = 1\text{mA}$ $I_Z = 100\mu\text{A}$	25°C			± 20			ppm/°C
			25°C			± 15			
			Full range			± 100			
			25°C			± 15			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.4 0.8			mV
			Full range			1.1 1.3			
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			2.7 6			
			Full range			9 11			
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.4 0.9			Ω
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			35			μV_{RMS}
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
 A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
 C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.14 LM4040A41I, LM4040B41I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040A41I			LM4040B41I			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			4.096			V	
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-4.1 4.1			mV	
			Full range			-31 31				
$I_{Z,\text{min}}$	Minimum cathode current		25°C			50 83			μA	
			Full range			88 88				
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 30			ppm/°C	
			$I_Z = 1\text{mA}$	25°C			± 20			
				Full range			± 100			
			$I_Z = 100\mu\text{A}$	25°C			± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.5 0.9			mV	
			Full range			1.2 1.2				
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			3 7				
			Full range			10 10				
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.5 1			Ω	
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			80			μV_{RMS}	
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm	
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—	

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.15 LM4040C41I, LM4040D41I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C41I			LM4040D41I			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			4.096			V	
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-20 20			mV	
			Full range			-47 47				
$I_{Z,\text{min}}$	Minimum cathode current		25°C			50 83			μA	
			Full range			88 88				
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 30			ppm/°C	
			$I_Z = 1\text{mA}$	25°C			± 20			
				Full range			± 100			
			$I_Z = 100\mu\text{A}$	25°C			± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.5 0.9			mV	
			Full range			1.2 1.5				
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			3 7				
			Full range			10 13				
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.5 1			Ω	
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			80			μV_{RMS}	
	Long-term stability of reverse breakdown voltage	$t = 1000\text{h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm	
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—	

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
 A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
 C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.16 LM4040A50I, LM4040B50I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040A50I			LM4040B50I			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			5			V	
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-5 5			mV	
			Full range			-38 38				
$I_{Z,\text{min}}$	Minimum cathode current		25°C			65 89			μA	
			Full range			95 95				
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 30			ppm/°C	
			$I_Z = 1\text{mA}$	25°C			± 20			
				Full range			± 100			
			$I_Z = 100\mu\text{A}$	25°C			± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.5 1			mV	
			Full range			1.4 1.4				
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			3.5 8				
			Full range			12 12				
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.5 1.1			Ω	
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			80			μV_{RMS}	
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm	
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—	

(1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .

(2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:

A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:

C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.17 LM4040C50I, LM4040D50I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C50I			LM4040D50I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			5			V
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-25 25			mV
			Full range			-58 58			
$I_{Z,\text{min}}$	Minimum cathode current		25°C			65 89			μA
			Full range			95 95			
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$ $I_Z = 1\text{mA}$ $I_Z = 100\mu\text{A}$	25°C			± 30			ppm/°C
			25°C			± 20			
			Full range			± 100			
			25°C			± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.5 1 0.5 1.3			mV
			Full range			1.4 1.8			
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			3.5 8 3.5 10			
			Full range			12 15			
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.5 1.1 0.5 1.5			Ω
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			80 80			μV_{RMS}
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120 120			ppm
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08% 0.08%			—

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C.
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
 A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
 C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.18 LM4040C50Q, LM4040D50Q Electrical Characteristics

at extended temperature range, full-range $T_A = -40^\circ\text{C}$ to 125°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C50Q			LM4040D50Q			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_Z	Reverse breakdown voltage	$I_Z = 100\mu\text{A}$	25°C			5			V	
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 100\mu\text{A}$	25°C			-25 25			mV	
			Full range			-75 75				
$I_{Z,\text{min}}$	Minimum cathode current		25°C			65 89			μA	
			Full range			95 95				
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$	25°C			± 30			ppm/°C	
			$I_Z = 1\text{mA}$	25°C			± 20			
				Full range			± 100			
			$I_Z = 100\mu\text{A}$	25°C			± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.5 1			mV	
			Full range			1.4 1.8				
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			3.5 8				
			Full range			12 12				
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.5 1.1			Ω	
e_N	Wideband noise	$I_Z = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			80			μV_{RMS}	
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 100\mu\text{A}$				120			ppm	
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—	

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.19 LM4040A82I, LM4040B82I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040A82I			LM4040B82I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reverse breakdown voltage	$I_Z = 150\mu\text{A}$	25°C			8.192			V
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 150\mu\text{A}$	25°C			-8.2 8.2			mV
			Full range			-61 61			
$I_{Z,\text{min}}$	Minimum cathode current		25°C			67 106			μA
			Full range			110 110			
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$ $I_Z = 1\text{mA}$ $I_Z = 150\mu\text{A}$	25°C			± 40			ppm/°C
			25°C			± 20			
			Full range			± 100			
			25°C			± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.6 1.3			mV
			Full range			2.5 2.5			
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			7 10			
			Full range			18 18			
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.6 1.5			Ω
e_N	Wideband noise	$I_Z = 150\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			130			μV_{RMS}
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 150\mu\text{A}$				120			ppm
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
 A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
 C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.20 LM4040C82I, LM4040D82I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040C82I			LM4040D82I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reverse breakdown voltage	$I_Z = 150\mu\text{A}$	25°C			8.192			V
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 150\mu\text{A}$	25°C			-41 41 -82 82			mV
			Full range			-94 94 -162 162			
$I_{Z,\text{min}}$	Minimum cathode current		25°C			67 106 67 111			μA
			Full range			110 115			
α_{VZ}	Average temperature coefficient of reverse breakdown voltage ⁽²⁾	$I_Z = 10\text{mA}$ $I_Z = 1\text{mA}$ $I_Z = 150\mu\text{A}$	25°C			± 40 ± 40			ppm/°C
			25°C			± 20 ± 20			
			Full range			± 100 ± 150			
			25°C			± 20 ± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.6 1.3 0.6 1.7			mV
			Full range			2.5 3			
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			7 10 7 15			
			Full range			18 24			
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.6 1.5 0.6 1.9			Ω
e_N	Wideband noise	$I_Z = 150\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			130 130			μV_{RMS}
	Long-term stability of reverse breakdown voltage	$t = 1000\text{h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 150\mu\text{A}$				120 120			ppm
V_{HYST}	Thermal hysteresis ⁽¹⁾	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08% 0.08%			—

(1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .

(2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:

A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$

The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:

C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$

Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

6.21 LM4040A10I, LM4040B10I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LM4040A10I			LM4040B10I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reverse breakdown voltage	$I_Z = 150\mu\text{A}$	25°C			10			V
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 150\mu\text{A}$	25°C			-10 10			mV
			Full range			-75 75			
$I_{Z,\text{min}}$	Minimum cathode current		25°C			75 120			μA
			Full range			125 125			
α_{VZ}	Average temperature coefficient of reverse breakdown voltage (2)	$I_Z = 10\text{mA}$ $I_Z = 1\text{mA}$ $I_Z = 150\mu\text{A}$	25°C			± 40			ppm/°C
			25°C			± 20			
			Full range			± 100			
			25°C			± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.8 1.5			mV
			Full range			3.5 3.5			
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			8 14			
			Full range			24 24			
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.7 1.7			Ω
e_N	Wideband noise	$I_Z = 150\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			180			μV_{RMS}
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 150\mu\text{A}$				120			ppm
V_{HYST}	Thermal hysteresis(1)	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
 A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
 The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
 C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
 Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

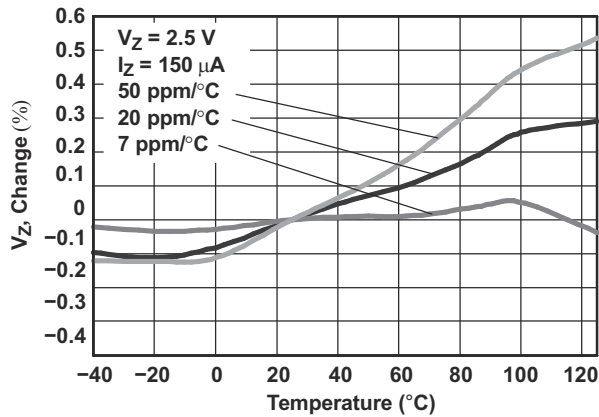
6.22 LM4040C10I, LM4040D10I Electrical Characteristics

at industrial temperature range, full-range $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)

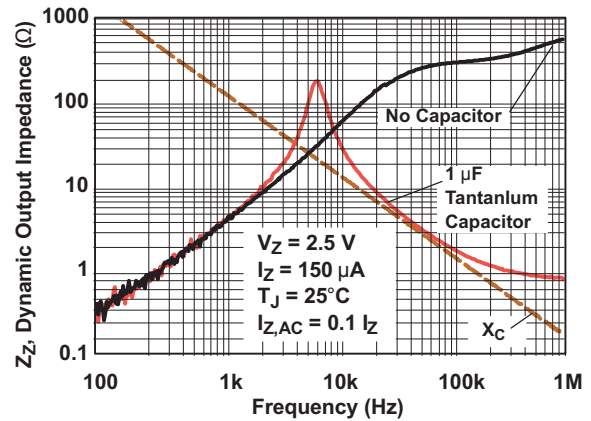
PARAMETER	TEST CONDITIONS	T_A	LM4040C10I			LM4040D10I			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_Z	Reverse breakdown voltage	$I_Z = 150\mu\text{A}$	25°C			10			V	
ΔV_Z	Reverse breakdown voltage tolerance	$I_Z = 150\mu\text{A}$	25°C			-50 50			mV	
			Full range			-115 115				
$I_{Z,\text{min}}$	Minimum cathode current		25°C			75 120			μA	
			Full range			125 135				
α_{VZ}	Average temperature coefficient of reverse breakdown voltage ⁽²⁾	$I_Z = 10\text{mA}$	25°C			± 40			ppm/°C	
			$I_Z = 1\text{mA}$	25°C			± 20			
				Full range			± 100			
			$I_Z = 150\mu\text{A}$	25°C			± 20			
$\frac{\Delta V_Z}{\Delta I_Z}$	Reverse breakdown voltage change with cathode current change	$I_{Z,\text{min}} < I_Z < 1\text{mA}$	25°C			0.8 1.5			mV	
			Full range			3.5 4				
		$1\text{mA} < I_Z < 15\text{mA}$	25°C			8 14				
			Full range			24 29				
Z_Z	Reverse dynamic impedance	$I_Z = 1\text{mA}$, $f = 120\text{Hz}$, $I_{AC} = 0.1 I_Z$	25°C			0.7 1.7			Ω	
e_N	Wideband noise	$I_Z = 150\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	25°C			180			μV_{RMS}	
	Long-term stability of reverse breakdown voltage	$t = 1000\text{ h}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$, $I_Z = 150\mu\text{A}$				120			ppm	
V_{HYST}	Thermal hysteresis ⁽¹⁾	$\Delta T_A = -40^\circ\text{C}$ to 125°C				0.08%			—	

- (1) Thermal hysteresis is defined as the difference in voltage measured at 25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature 125°C .
- (2) The overtemperature limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm[(\Delta V_R/\Delta T)(\text{max}\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\text{max}\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total overtemperature tolerance for the different grades in the industrial temperature range where $\text{max}\Delta T = 65^\circ\text{C}$ is shown below:
A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 65^\circ\text{C}$
The total overtemperature tolerance for the different grades in the extended temperature range where $\text{max}\Delta T = 100^\circ\text{C}$ is shown below:
C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150\text{ppm}/^\circ\text{C} \times 100^\circ\text{C}$
Therefore, as an example, the A-grade 2.5V LM4040 has an overtemperature Reverse Breakdown Voltage tolerance of $\pm 2.5\text{V} \times 0.75\% = \pm 19\text{mV}$.

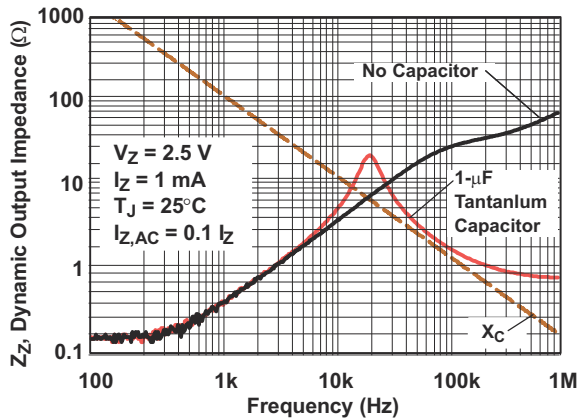
6.23 Typical Characteristics



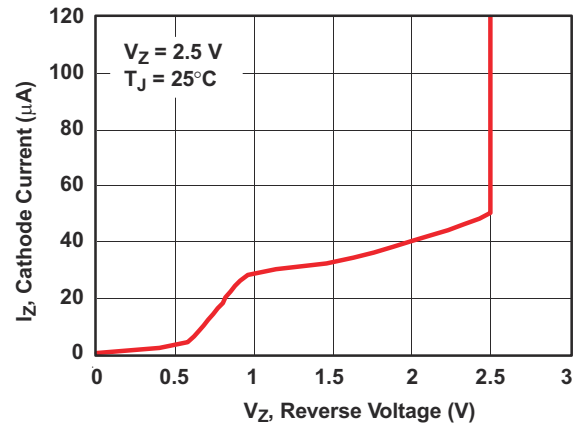
6-1. Temperature Drift for Different Average Temperature Coefficients



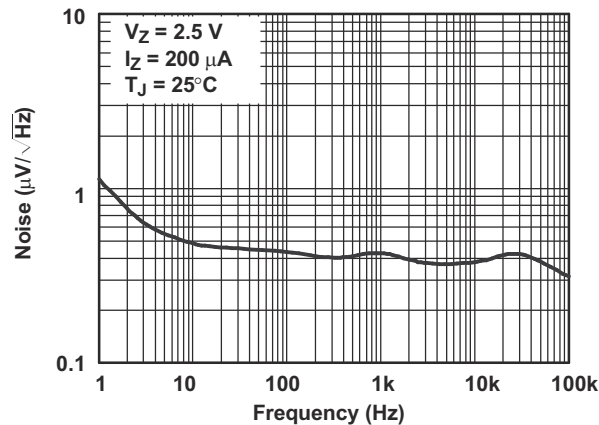
6-2. Output Impedance vs Frequency



6-3. Output Impedance vs Frequency



6-4. Cathode Current vs. Reverse Voltage



6-5. Noise Voltage vs Frequency

7 Detailed Description

7.1 Overview

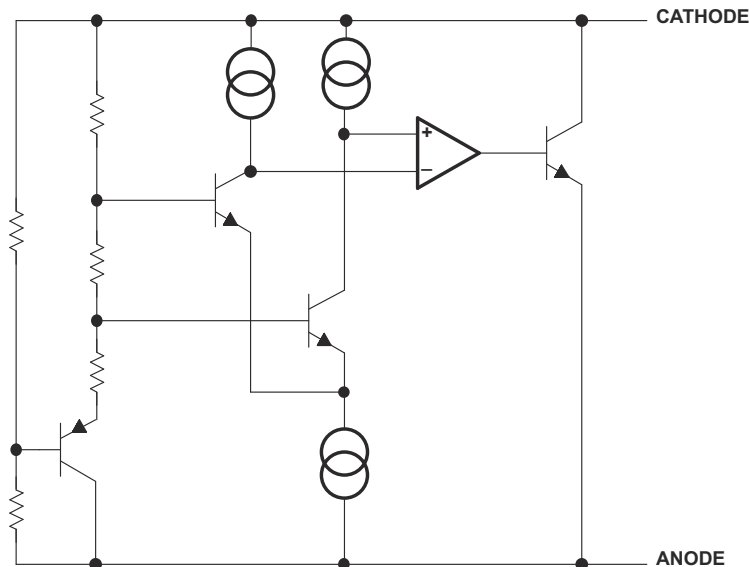
The LM4040 is a precision micro-power curvature-corrected bandgap shunt voltage reference. The LM4040 has been designed for stable operation without the need of an external capacitor connected between the “+” pin and the “-” pin. If, however, a bypass capacitor is used, the LM4040 remains stable.

LM4040 offers several fixed reverse breakdown voltages: 2.048V, 2.500V, 3.000V, 4.096V, 5.000V, 6.000, 8.192V, and 10.000V. The minimum operating current increases from 60 μ A for the LM4040-N-2.048 and LM4040-N-2.5 to 100 μ A for the 10.0-V LM4040. All versions have a maximum operating current of 15mA.

Each reverse voltage options can be purchased with initial tolerances (at 25°C) of 0.1%, 0.2%, 0.5% and 1.0%. These reference options are denoted by A (0.1%), B (0.2%), C (0.5%) and D for (1.0%).

The LM4040xxxI devices are characterized for operation from -40°C to 85°C, and the LM4040xxxQ devices are characterized for operation from -40°C to 125°C.

7.2 Functional Block Diagram



7.3 Feature Description

A temperature compensated band gap voltage reference controls high gain amplifier and shunt pass element to maintain a nearly constant voltage between cathode and anode. Regulation occurs after a minimum current is provided to power the voltage divider and amplifier. Internal frequency compensation provides a stable loop for all capacitor loads. Floating shunt design is useful for both positive and negative regulation applications.

7.4 Device Functional Modes

7.4.1 Shunt Reference

LM4040 does not operate in one mode, which is as a fixed voltage reference that cannot be adjusted. LM4040 does offer various Reverse Voltage options that have unique electrical characteristics detailed in [セクション 6](#).

For a proper Reverse Voltage to be developed, current must be sourced into the cathode of LM4040. The minimum current needed for proper regulation is denoted in [セクション 6](#) as $I_{Z,min}$.

8 Applications and Implementation

注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくこととなります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

8.1 Application Information

LM4040 is a well known industry standard device used in several applications and end equipment where a reference is required. Below describes this device being used in a data acquisition system. Analog to Digital conversion systems are the most common applications to use LM4040 due to its low reference tolerance which allows high precision in these systems.

8.2 Typical Applications

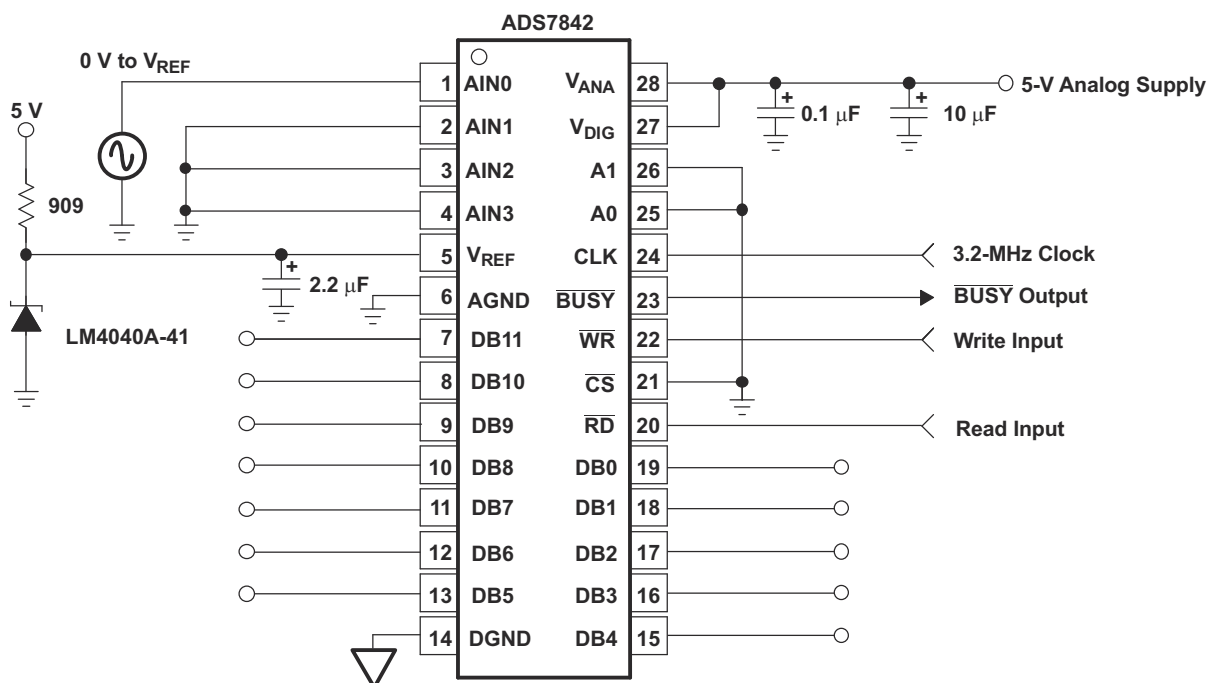


図 8-1. Data-Acquisition Circuit With LM4040x-41

8.2.1 Design Requirements

For this design example, use the parameters listed in 表 8-1 as the input parameters.

表 8-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
ADC FSR (Full Scale Range)	4.096
ADC Resolution	12 Bits
Supply Voltage	5V
Cathode Current (Ik)	100 µA

8.2.2 Detailed Design Procedure

When using LM4040 as a comparator with reference, determine the following:

- Input voltage range
- Reference voltage accuracy
- Output logic input high and low level thresholds
- Current source resistance

8.2.2.1 LM4040 Voltage and Accuracy Choice

When using LM4040 as a reference for an ADC, the ADC's FSR (Full Scale Range), Resolution and LSB must be determined. LSB can be determined by:

$$\text{LSB} = \text{FSR} / (2^N - 1)$$

With N being the resolution or Number of Bits. FSR and Resolution can be determined by the ADC's datasheet.

Vref can be determined by:

$$\text{Vref} = \text{FSR} + \text{LSB}$$

Though modern data converters use calibration techniques to compensate for any error introduced by a Vref's inaccuracy, it is best to use the highest accuracy available. This is due to errors in the calibration method that may allow some non-linearities introduced by the Vref's initial accuracy.

A good example is the LM4040x-41 that is designed to be a cost-effective voltage reference as required in 12-bit data-acquisition systems. For 12-bit systems operating from 5-V supplies (see [Figure 8-1](#)), the LM4040A-41 (4.096V, 0.01%) only introduces 4 LSBs (4mV) of possible error in a system that consists of 4096 LSBs.

8.2.2.2 Cathode and Load Currents

In a typical shunt-regulator configuration (see [Figure 8-2](#)), an external resistor, R_S , is connected between the supply and the cathode of the LM4040. R_S must be set properly, as it sets the total current available to supply the load (I_L) and bias the LM4040 (I_Z). In all cases, I_Z must stay within a specified range for proper operation of the reference. Taking into consideration one extreme in the variation of the load and supply voltage (maximum I_L and minimum V_S), R_S must be small enough to supply the minimum I_Z required for operation of the regulator, as given by data-sheet parameters. At the other extreme, maximum V_S and minimum I_L , R_S must be large enough to limit I_Z to less than its maximum-rated value of 15mA.

R_S is calculated according to [Equation 1](#):

$$R_S = \frac{(V_S - V_Z)}{(I_L + I_Z)} \quad (1)$$

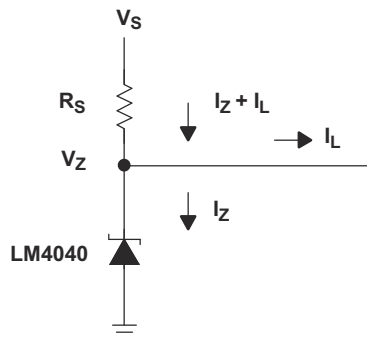


Figure 8-2. Shunt Regulator

8.2.2.3 Output Capacitor

The LM4040 does not require an output capacitor across cathode and anode for stability. However, if an output bypass capacitor is desired, the LM4040 is designed to be stable with all capacitive loads.

8.2.2.4 SOT-23 Connections

There is a parasitic Schottky diode connected between pins 2 and 3 of the SOT-23 packaged device. Thus, pin 3 of the SOT-23 package must be left floating or connected to pin 2.

8.2.2.5 Start-Up Characteristics

In any data conversion system, start-up characteristics are important, as to determine when it is safe begin conversion based upon a steady and settled reference value. As shown in [Figure 8-4](#) it is best to allow for >20 μ s from supply start-up to begin conversion.

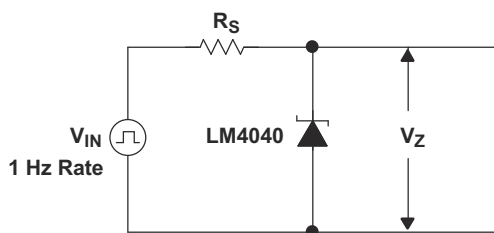


Figure 8-3. Test Circuit

8.2.3 Application Curve

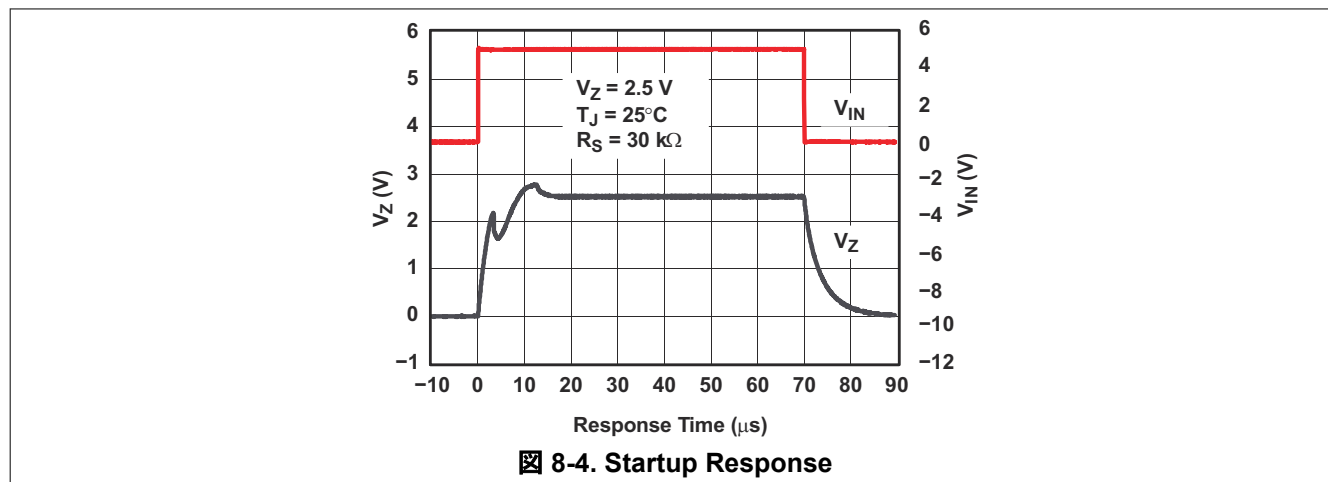


Figure 8-4. Startup Response

8.3 Power Supply Recommendations

To not exceed the maximum cathode current, be sure that the supply voltage is current limited.

For applications shunting high currents (15mA max), pay attention to the cathode and anode trace lengths, adjusting the width of the traces to have the proper current density.

8.4 Layout

8.4.1 Layout Guidelines

[Figure 8-5](#) shows an example of a PCB layout of LM4040XXXDBZ. Some key V_{ref} noise considerations are:

- Connect a low-ESR, 0.1- μ F (C_L) ceramic bypass capacitor on the cathode pin node.
- Decouple other active devices in the system per the device specifications.
- Using a solid ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise pickup.

- Place the external components as close to the device as possible. This configuration prevents parasitic errors (such as the Seebeck effect) from occurring.
- Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible and only make perpendicular crossings when absolutely necessary.

8.4.2 Layout Example

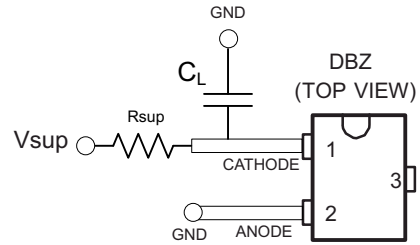


图 8-5. DBZ Layout example

9 Device and Documentation Support

9.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

表 9-1. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LM4040A	Click here	Click here	Click here	Click here	Click here
LM4040B	Click here	Click here	Click here	Click here	Click here
LM4040C	Click here	Click here	Click here	Click here	Click here
LM4040D	Click here	Click here	Click here	Click here	Click here

9.2 Trademarks

すべての商標は、それぞれの所有者に帰属します。

9.3 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

9.4 用語集

[テキサス・インスツルメンツ用語集](#)

この用語集には、用語や略語の一覧および定義が記載されています。

10 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision N (October 2017) to Revision O (June 2024) Page

- ドキュメント全体にわたって表、図、相互参照の採番方法を更新。..... 1
- Updated pinout diagrams 4

Changes from Revision M (January 2015) to Revision N (October 2017) Page

- 標準型番を変更しより短いリスト (LM4040A/B/C/D) を追加..... 1
- Added Average temperature coefficient of reverse breakdown voltage footnote to all electrical tables..... 6
- Changed Thermal hysteresis in electrical characteristics tables..... 6

Changes from Revision L (January 2009) to Revision M (January 2015) Page

- 「アプリケーション」セクション、「製品情報」表、「端子機能」表、「ESD 定格」表、「熱に関する情報」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加..... 1
- 「注文情報」表を削除。..... 1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

重要なお知らせと免責事項

テキサス・インスツルメンツは、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、テキサス・インスツルメンツ製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した テキサス・インスツルメンツ製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている テキサス・インスツルメンツ製品を使用するアプリケーションの開発の目的でのみ、テキサス・インスツルメンツはその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。テキサス・インスツルメンツや第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、テキサス・インスツルメンツおよびその代理人を完全に補償するものとし、テキサス・インスツルメンツは一切の責任を拒否します。

テキサス・インスツルメンツの製品は、[テキサス・インスツルメンツの販売条件](#)、または [ti.com](https://www.ti.com) やかかる テキサス・インスツルメンツ製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。テキサス・インスツルメンツがこれらのリソースを提供することは、適用されるテキサス・インスツルメンツの保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、テキサス・インスツルメンツはそれらに異議を唱え、拒否します。

郵送先住所: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

Copyright © 2024, Texas Instruments Incorporated

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM4040A10IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NQ3, 4NQU)	Samples
LM4040A10IDBZR1G4	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NQ3, 4NQU)	Samples
LM4040A10IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NQ3, 4NQU)	Samples
LM4040A10IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PHU	Samples
LM4040A20IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(4MC3, 4MCU)	Samples
LM4040A20IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MC3, 4MCU)	Samples
LM4040A20IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MSU	Samples
LM4040A25IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(4NG3, 4NGU)	Samples
LM4040A25IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NG3, 4NGU)	Samples
LM4040A25IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	P2U	Samples
LM4040A30IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(4M63, 4M6U)	Samples
LM4040A30IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M63, 4M6U)	Samples
LM4040A30IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	P9U	Samples
LM4040A41IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(4M23, 4M2U)	Samples
LM4040A41IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M23, 4M2U)	Samples
LM4040A41IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	P4U	Samples
LM4040A50IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(4NA3, 4NAU)	Samples
LM4040A50IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NA3, 4NAU)	Samples
LM4040A50IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	N5U	Samples
LM4040A82IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NL3, 4NLU)	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM4040A82IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NL3, 4NLU)	Samples
LM4040A82IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PDU	Samples
LM4040B10IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NR3, 4NRU)	Samples
LM4040B10IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NR3, 4NRU)	Samples
LM4040B10IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PJU	Samples
LM4040B20IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MD3, 4MDU)	Samples
LM4040B20IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MD3, 4MDU)	Samples
LM4040B20IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(MTS, MTU)	Samples
LM4040B25IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NH3, 4NHU)	Samples
LM4040B25IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NH3, 4NHU)	Samples
LM4040B25IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	P3U	Samples
LM4040B30IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M73, 4M7U)	Samples
LM4040B30IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M73, 4M7U)	Samples
LM4040B30IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	PAU	Samples
LM4040B30IDCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PAU	Samples
LM4040B41IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M33, 4M3U)	Samples
LM4040B41IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M33, 4M3U)	Samples
LM4040B41IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	P5U	Samples
LM4040B50IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NB3, 4NBU)	Samples
LM4040B50IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NB3, 4NBU)	Samples
LM4040B50IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MXU	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM4040B82IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NM3, 4NMU)	Samples
LM4040C10IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NS3, 4NSU)	Samples
LM4040C10IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NS3, 4NSU)	Samples
LM4040C10IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PKU	Samples
LM4040C10ILP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	-40 to 85	NFC10I	
LM4040C10ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC10I	Samples
LM4040C20IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MQ3, 4MQU)	Samples
LM4040C20IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MQ3, 4MQU)	Samples
LM4040C20IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MVU	Samples
LM4040C20ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC20I	Samples
LM4040C20ILPE3	ACTIVE	TO-92	LP	3	1000	TBD	Call TI	Call TI	-40 to 85		Samples
LM4040C20ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC20I	Samples
LM4040C20QDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4MW3, 4MWU)	Samples
LM4040C20QDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4MW3, 4MWU)	Samples
LM4040C25IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MU3, 4MUU)	Samples
LM4040C25IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MU3, 4MUU)	Samples
LM4040C25IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MUU	Samples
LM4040C25IDCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	MUU	Samples
LM4040C25ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC25I	Samples
LM4040C25ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC25I	Samples
LM4040C25QDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4MA3, 4MAU)	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM4040C25QDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4MA3, 4MAU)	Samples
LM4040C30IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M83, 4M8U)	Samples
LM4040C30IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M83, 4M8U)	Samples
LM4040C30IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	PBU	Samples
LM4040C30ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC30I	Samples
LM4040C30ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC30I	Samples
LM4040C30QDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4NJ3, 4NJU)	Samples
LM4040C30QDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4NJ3, 4NJU)	Samples
LM4040C41IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M43, 4M4U)	Samples
LM4040C41IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M43, 4M4U)	Samples
LM4040C41IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	P6U	Samples
LM4040C41ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC41I	Samples
LM4040C41ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC41I	Samples
LM4040C50IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NC3, 4NCU)	Samples
LM4040C50IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NC3, 4NCU)	Samples
LM4040C50IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MZU	Samples
LM4040C50ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC50I	Samples
LM4040C50ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC50I	Samples
LM4040C50QDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4NE3, 4NEU)	Samples
LM4040C50QDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4NE3, 4NEU)	Samples
LM4040C82IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NN3, 4NNU)	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM4040C82IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PFU	Samples
LM4040C82IDCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PFU	Samples
LM4040C82ILP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	-40 to 85	NFC82I	
LM4040C82ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFC82I	Samples
LM4040D10IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NT3, 4NTU)	Samples
LM4040D10IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NT3, 4NTU)	Samples
LM4040D10IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PLU	Samples
LM4040D10IDCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PLU	Samples
LM4040D10ILP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	-40 to 85	NFD10I	
LM4040D20IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MV3, 4MVU)	Samples
LM4040D20IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4MV3, 4MVU)	Samples
LM4040D20IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MWU	Samples
LM4040D20ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD20I	Samples
LM4040D20ILPRE3	ACTIVE	TO-92	LP	3	2000	TBD	Call TI	Call TI	-40 to 85		Samples
LM4040D20QDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4MY3, 4MYU)	Samples
LM4040D20QDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4MY3, 4MYU)	Samples
LM4040D25IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4ME3, 4MEU)	Samples
LM4040D25IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4ME3, 4MEU)	Samples
LM4040D25IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MEU	Samples
LM4040D25IDCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MEU	Samples
LM4040D25ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD25I	Samples
LM4040D25ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD25I	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM4040D25QDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4MB3, 4MBU)	Samples
LM4040D25QDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4MB3, 4MBU)	Samples
LM4040D30IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M93, 4M9U)	Samples
LM4040D30IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M93, 4M9U)	Samples
LM4040D30IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PCU	Samples
LM4040D30IDCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PCU	Samples
LM4040D30ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD30I	Samples
LM4040D30ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD30I	Samples
LM4040D30ILPRE3	ACTIVE	TO-92	LP	3	2000	TBD	Call TI	Call TI	-40 to 85		Samples
LM4040D30QDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4NK3, 4NKU)	Samples
LM4040D41IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M53, 4M5U)	Samples
LM4040D41IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4M53, 4M5U)	Samples
LM4040D41IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	P7U	Samples
LM4040D41ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD41I	Samples
LM4040D41ILPE3	ACTIVE	TO-92	LP	3	1000	TBD	Call TI	Call TI	-40 to 85		Samples
LM4040D41ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD41I	Samples
LM4040D50IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4ND3, 4NDU)	Samples
LM4040D50IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4ND3, 4NDU)	Samples
LM4040D50IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	M4U	Samples
LM4040D50ILP	ACTIVE	TO-92	LP	3	1000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD50I	Samples
LM4040D50ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD50I	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM4040D50ILPRE3	ACTIVE	TO-92	LP	3	2000	TBD	Call TI	Call TI	-40 to 85		Samples
LM4040D50QDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4NF3, 4NFU)	Samples
LM4040D50QDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(4NF3, 4NFU)	Samples
LM4040D82IDBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NP3, 4NPU)	Samples
LM4040D82IDBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(4NP3, 4NPU)	Samples
LM4040D82IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PGU	Samples
LM4040D82ILP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI	-40 to 85	NFD82I	
LM4040D82ILPR	ACTIVE	TO-92	LP	3	2000	RoHS & Green	SN	N / A for Pkg Type	-40 to 85	NFD82I	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM4040A10IDBZR	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040A10IDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040A10IDBZR1G4	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040A10IDBZR1G4	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040A10IDBZT	SOT-23	DBZ	3	250	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040A10IDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040A10IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040A20IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A20IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A20IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040A25IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A25IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A25IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040A25IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040A30IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A30IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM4040A30IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040A41IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A41IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A41IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040A41IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040A50IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A50IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040A50IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040A82IDBZR	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040A82IDBZT	SOT-23	DBZ	3	250	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040A82IDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040A82IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040B10IDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040B10IDBZR	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040B10IDBZT	SOT-23	DBZ	3	250	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040B10IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040B20IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B20IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B20IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040B25IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B25IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B25IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040B25IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040B30IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B30IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B30IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040B30IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040B30IDCKRG4	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040B41IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B41IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B41IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040B41IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040B50IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B50IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040B50IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040B82IDBZR	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040C10IDBZR	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040C10IDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040C10IDBZT	SOT-23	DBZ	3	250	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040C10IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040C20IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM4040C20IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C20IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040C20QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C20QDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C25IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C25IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C25IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040C25IDCKT	SC70	DCK	5	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040C25IDCKT	SC70	DCK	5	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040C25QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C25QDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C30IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C30IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C30IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040C30IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040C30QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C30QDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C41IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C41IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C41IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040C41IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040C50IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C50IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C50IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040C50QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C50QDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040C82IDBZR	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040C82IDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040C82IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040C82IDCKRG4	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D10IDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040D10IDBZR	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040D10IDBZT	SOT-23	DBZ	3	250	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040D10IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D10IDCKRG4	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D20IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D20IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D20IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D20QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D20QDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D25IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM4040D25IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D25IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D25IDCKT	SC70	DCK	5	250	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D25QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D25QDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D30IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D30IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D30IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D30IDCKRG4	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D30QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D41IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D41IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D41IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D41IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LM4040D50IDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D50IDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D50IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3
LM4040D50QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D50QDBZT	SOT-23	DBZ	3	250	180.0	8.4	2.9	3.35	1.35	4.0	8.0	Q3
LM4040D82IDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040D82IDBZR	SOT-23	DBZ	3	3000	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040D82IDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
LM4040D82IDBZT	SOT-23	DBZ	3	250	178.0	9.2	3.15	2.77	1.22	4.0	8.0	Q3
LM4040D82IDCKR	SC70	DCK	5	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM4040A10IDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040A10IDBZR	SOT-23	DBZ	3	3000	200.0	183.0	25.0
LM4040A10IDBZR1G4	SOT-23	DBZ	3	3000	200.0	183.0	25.0
LM4040A10IDBZR1G4	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040A10IDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
LM4040A10IDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
LM4040A10IDCKR	SC70	DCK	5	3000	203.0	203.0	35.0
LM4040A20IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040A20IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040A20IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040A25IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040A25IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040A25IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040A25IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040A30IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040A30IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040A30IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040A41IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM4040A41IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040A41IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040A41IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040A50IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040A50IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040A50IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040A82IDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040A82IDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
LM4040A82IDBZT	SOT-23	DBZ	3	250	200.0	183.0	25.0
LM4040A82IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040B10IDBZR	SOT-23	DBZ	3	3000	200.0	183.0	25.0
LM4040B10IDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040B10IDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
LM4040B10IDCKR	SC70	DCK	5	3000	203.0	203.0	35.0
LM4040B20IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040B20IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040B20IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040B25IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040B25IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040B25IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040B25IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040B30IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040B30IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040B30IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040B30IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040B30IDCKRG4	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040B41IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040B41IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040B41IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040B41IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040B50IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040B50IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040B50IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040B82IDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040C10IDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040C10IDBZR	SOT-23	DBZ	3	3000	200.0	183.0	25.0
LM4040C10IDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
LM4040C10IDCKR	SC70	DCK	5	3000	203.0	203.0	35.0
LM4040C20IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C20IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040C20IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040C20QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C20QDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM4040C25IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C25IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040C25IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040C25IDCKT	SC70	DCK	5	250	210.0	185.0	35.0
LM4040C25IDCKT	SC70	DCK	5	250	200.0	183.0	25.0
LM4040C25QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C25QDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040C30IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C30IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040C30IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040C30IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040C30QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C30QDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040C41IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C41IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040C41IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040C41IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040C50IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C50IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040C50IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040C50QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040C50QDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040C82IDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040C82IDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
LM4040C82IDCKR	SC70	DCK	5	3000	203.0	203.0	35.0
LM4040C82IDCKRG4	SC70	DCK	5	3000	203.0	203.0	35.0
LM4040D10IDBZR	SOT-23	DBZ	3	3000	200.0	183.0	25.0
LM4040D10IDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040D10IDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
LM4040D10IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040D10IDCKRG4	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040D20IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040D20IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040D20IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040D20QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040D20QDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040D25IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040D25IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040D25IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040D25IDCKT	SC70	DCK	5	250	200.0	183.0	25.0
LM4040D25QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040D25QDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040D30IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0

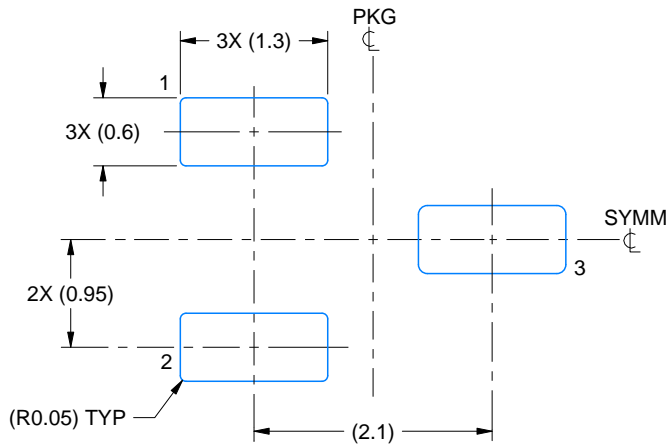
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM4040D30IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040D30IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040D30IDCKRG4	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040D30QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040D41IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040D41IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040D41IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040D41IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LM4040D50IDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040D50IDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040D50IDCKR	SC70	DCK	5	3000	200.0	183.0	25.0
LM4040D50QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM4040D50QDBZT	SOT-23	DBZ	3	250	210.0	185.0	35.0
LM4040D82IDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
LM4040D82IDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
LM4040D82IDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
LM4040D82IDBZT	SOT-23	DBZ	3	250	180.0	180.0	18.0
LM4040D82IDCKR	SC70	DCK	5	3000	203.0	203.0	35.0

EXAMPLE BOARD LAYOUT

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
SCALE:15X



SOLDER MASK DETAILS

4214838/F 08/2024

NOTES: (continued)

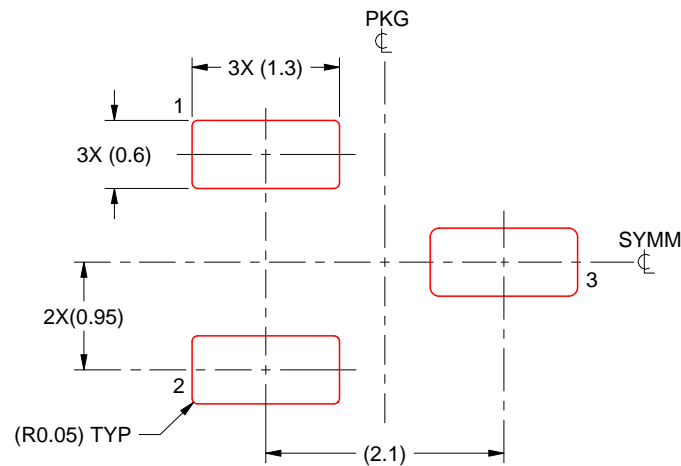
- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214838/F 08/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

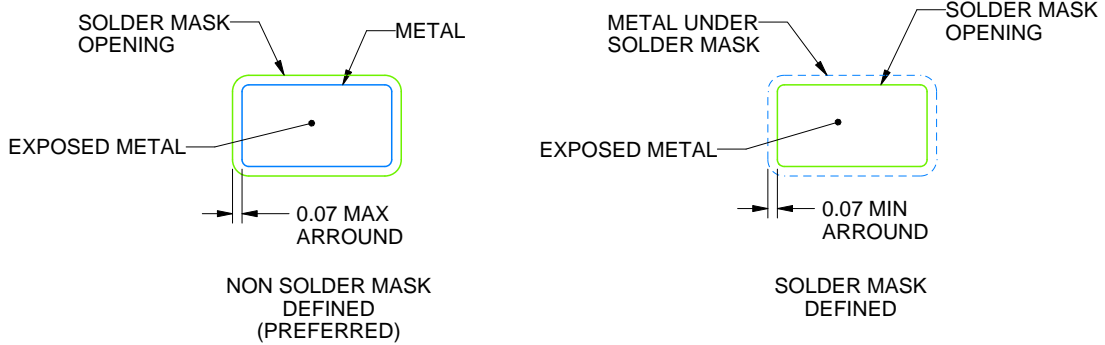
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X



SOLDER MASK DETAILS

4214834/G 11/2024

NOTES: (continued)

- 7. Publication IPC-7351 may have alternate designs.
- 8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE: 18X

4214834/G 11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

LP 3

TO-92 - 5.34 mm max height

TRANSISTOR OUTLINE



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4040001-2/F

LP0003A



PACKAGE OUTLINE

TO-92 - 5.34 mm max height

TO-92



4215214/B 04/2017

NOTES:

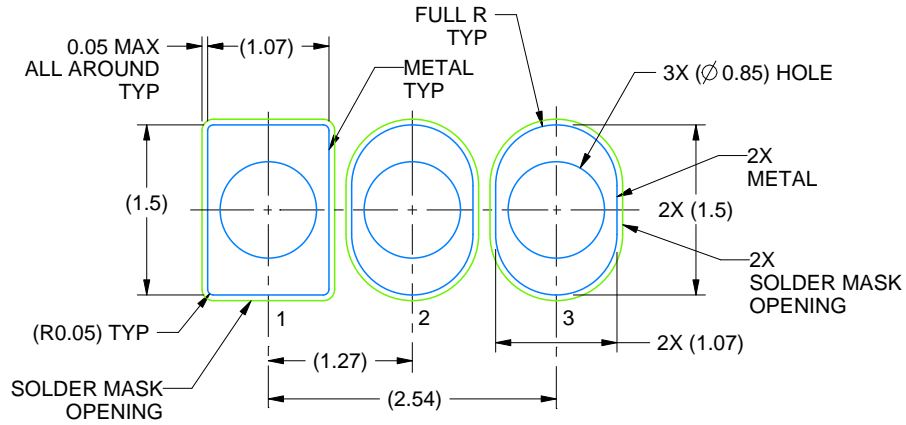
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Lead dimensions are not controlled within this area.
4. Reference JEDEC TO-226, variation AA.
5. Shipping method:
 - a. Straight lead option available in bulk pack only.
 - b. Formed lead option available in tape and reel or ammo pack.
 - c. Specific products can be offered in limited combinations of shipping medium and lead options.
 - d. Consult product folder for more information on available options.

EXAMPLE BOARD LAYOUT

LP0003A

TO-92 - 5.34 mm max height

TO-92



LAND PATTERN EXAMPLE
STRAIGHT LEAD OPTION
NON-SOLDER MASK DEFINED
SCALE:15X



LAND PATTERN EXAMPLE
FORMED LEAD OPTION
NON-SOLDER MASK DEFINED
SCALE:15X

4215214/B 04/2017

TAPE SPECIFICATIONS

LP0003A

TO-92 - 5.34 mm max height

TO-92



FOR FORMED LEAD OPTION PACKAGE

4215214/B 04/2017

重要なお知らせと免責事項

テキサス・インスツルメンツは、技術データと信頼性データ(データシートを含みます)、設計リソース(リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、テキサス・インスツルメンツ製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適したテキサス・インスツルメンツ製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとし、ます。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されているテキサス・インスツルメンツ製品を使用するアプリケーションの開発の目的でのみ、テキサス・インスツルメンツはその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。テキサス・インスツルメンツや第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、テキサス・インスツルメンツおよびその代理人を完全に補償するものとし、テキサス・インスツルメンツは一切の責任を拒否します。

テキサス・インスツルメンツの製品は、[テキサス・インスツルメンツの販売条件](#)、または [ti.com](https://www.ti.com) やかかるテキサス・インスツルメンツ製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。テキサス・インスツルメンツがこれらのリソースを提供することは、適用されるテキサス・インスツルメンツの保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、テキサス・インスツルメンツはそれらに異議を唱え、拒否します。

郵送先住所：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2025, Texas Instruments Incorporated